

## NCE N-Channel Super Trench Power MOSFET

### Description

The NCEP0178AK uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### General Features

- $V_{DS} = 100V, I_D = 78A$   
 $R_{DS(ON)} = 7.2m\Omega$  (typical) @  $V_{GS} = 10V$   
 $R_{DS(ON)} = 9.5m\Omega$  (typical) @  $V_{GS} = 4.5V$
- Excellent gate charge x  $R_{DS(on)}$  product (FOM)
- Very low on-resistance  $R_{DS(on)}$
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested

### Application

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

**100% UIS TESTED!**

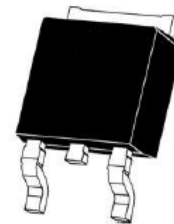
**100%  $\Delta V_{ds}$  TESTED!**



Schematic diagram



Marking and pin assignment



TO-252-2L top view

### Package Marking and Ordering Information

| Device Marking | Device     | Device Package | Reel Size | Tape width | Quantity |
|----------------|------------|----------------|-----------|------------|----------|
| NCEP0178AK     | NCEP0178AK | TO-252-2L      | -         | -          | -        |

### Absolute Maximum Ratings ( $T_C = 25^\circ C$ unless otherwise noted)

| Parameter   | Symbol             | Limit      | Unit          |
|---|--------------------|------------|---------------|
| Drain-Source Voltage                              | $V_{DS}$           | 100        | V             |
| Gate-Source Voltage                               | $V_{GS}$           | $\pm 20$   | V             |
| Drain Current-Continuous                          | $I_D$              | 78         | A             |
| Drain Current-Continuous ( $T_C = 100^\circ C$ )  | $I_D(100^\circ C)$ | 60         | A             |
| Pulsed Drain Current                              | $I_{DM}$           | 320        | A             |
| Maximum Power Dissipation                         | $P_D$              | 125        | W             |
| Derating factor                                   |                    | 0.83       | W/ $^\circ C$ |
| Single pulse avalanche energy <sup>(Note 5)</sup> | $E_{AS}$           | 320        | mJ            |
| Operating Junction and Storage Temperature Range  | $T_J, T_{STG}$     | -55 To 175 | $^\circ C$    |

**Thermal Characteristic**

|  |                 |     |               |
|--|-----------------|-----|---------------|
| Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup> | $R_{\theta JC}$ | 1.2 | $^{\circ}C/W$ |
|--|-----------------|-----|---------------|

**Electrical Characteristics ( $T_C=25^{\circ}C$  unless otherwise noted)**

| Parameter  | Symbol       | Condition  | Min | Typ  | Max       | Unit       |
|--|--------------|--|-----|------|-----------|------------|
| <b>Off Characteristics</b>                           |              |  |     |      |           |            |
| Drain-Source Breakdown Voltage                       | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$  | 100 |      | -         | V          |
| Zero Gate Voltage Drain Current                      | $I_{DSS}$    | $V_{DS}=100V, V_{GS}=0V$   | -   | -    | 1         | $\mu A$    |
| Gate-Body Leakage Current                            | $I_{GSS}$    | $V_{GS}=\pm 20V, V_{DS}=0V$  | -   | -    | $\pm 100$ | nA         |
| <b>On Characteristics</b> <sup>(Note 3)</sup>        |              |  |     |      |           |            |
| Gate Threshold Voltage                               | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$  | 1.2 | 1.7  | 2.2       | V          |
| Drain-Source On-State Resistance                     | $R_{DS(on)}$ | $V_{GS}=10V, I_D=39A$  | -   | 7.2  | 8.5       | m $\Omega$ |
|  |              | $V_{GS}=4.5V, I_D=39A$   | -   | 9.5  | 12        | m $\Omega$ |
| Forward Transconductance                             | $g_{FS}$     | $V_{DS}=10V, I_D=39A$  | 40  | -    | -         | S          |
| <b>Dynamic Characteristics</b> <sup>(Note 4)</sup>   |              |  |     |      |           |            |
| Input Capacitance                                    | $C_{iss}$    | $V_{DS}=50V, V_{GS}=0V,$<br>$F=1.0MHz$                                     | -   | 4200 | 5480      | PF         |
| Output Capacitance                                   | $C_{oss}$    |  | -   | 354  | 425       | PF         |
| Reverse Transfer Capacitance                         | $C_{rss}$    |  | -   | 23   | 30        | PF         |
| <b>Switching Characteristics</b> <sup>(Note 4)</sup> |              |  |     |      |           |            |
| Turn-on Delay Time                                   | $t_{d(on)}$  | $V_{DD}=50V, I_D=39A$<br>$V_{GS}=10V, R_G=4.7\Omega$                       | -   | 15   | -         | nS         |
| Turn-on Rise Time                                    | $t_r$        |  | -   | 10   | -         | nS         |
| Turn-Off Delay Time                                  | $t_{d(off)}$ |  | -   | 41   | -         | nS         |
| Turn-Off Fall Time                                   | $t_f$        |  | -   | 6    | -         | nS         |
| Total Gate Charge                                    | $Q_g$        | $V_{DS}=50V, I_D=39A,$<br>$V_{GS}=10V$                                     | -   | 65   |           | nC         |
| Gate-Source Charge                                   | $Q_{gs}$     |  | -   | 15.3 |           | nC         |
| Gate-Drain Charge                                    | $Q_{gd}$     |  | -   | 9    |           | nC         |
| <b>Drain-Source Diode Characteristics</b>            |              |  |     |      |           |            |
| Diode Forward Voltage <sup>(Note 3)</sup>            | $V_{SD}$     | $V_{GS}=0V, I_S=78A$   | -   |      | 1.2       | V          |
| Diode Forward Current <sup>(Note 2)</sup>            | $I_S$        |  | -   | -    | 78        | A          |
| Reverse Recovery Time                                | $t_{rr}$     | $T_J = 25^{\circ}C, I_F = I_S$<br>$di/dt = 100A/\mu s$ <sup>(Note 3)</sup> | -   | 101  |           | nS         |
| Reverse Recovery Charge                              | $Q_{rr}$     |  | -   | 193  |           | nC         |

**Notes:**

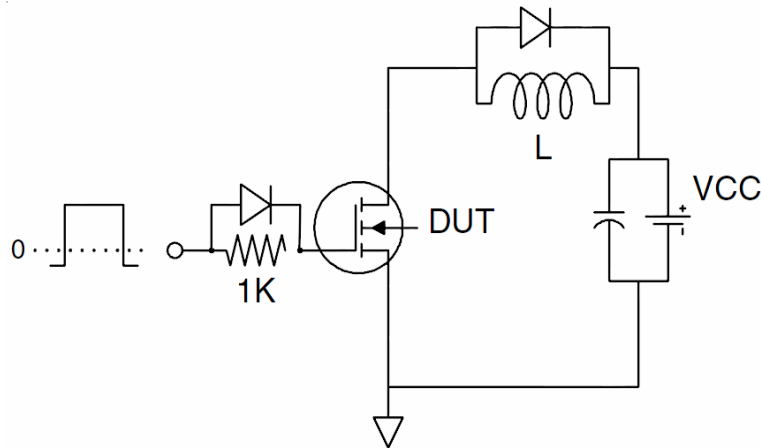
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec.
3. Pulse Test: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production
5. EAS condition :  $T_J=25^{\circ}C, V_{DD}=50V, V_G=10V, L=0.5mH, R_g=25\Omega$

**Test Circuit**

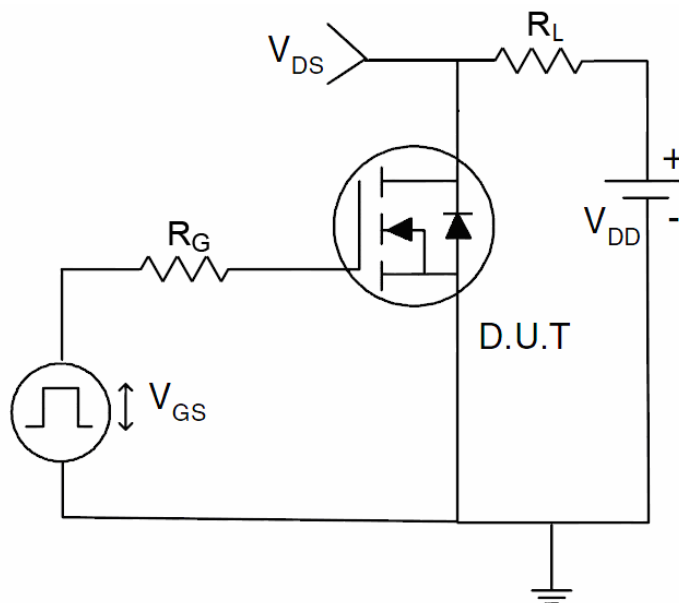
**1) E<sub>AS</sub> test Circuit**



**2) Gate charge test Circuit**



**3) Switch Time Test Circuit**



Typical Electrical and Thermal Characteristics

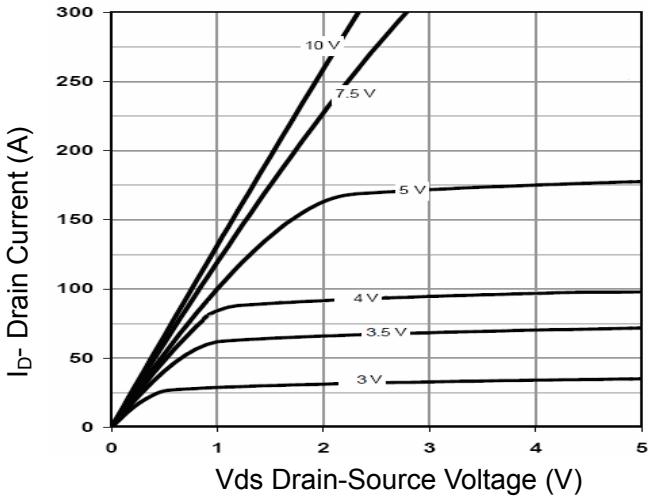


Figure 1 Output Characteristics

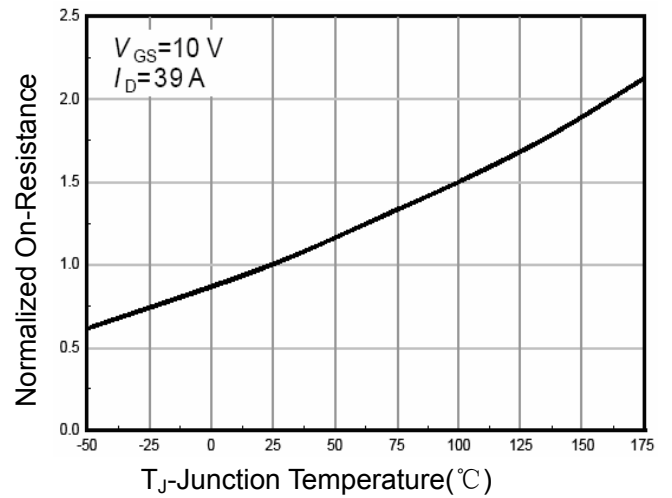


Figure 4  $R_{dson}$ -Junction Temperature

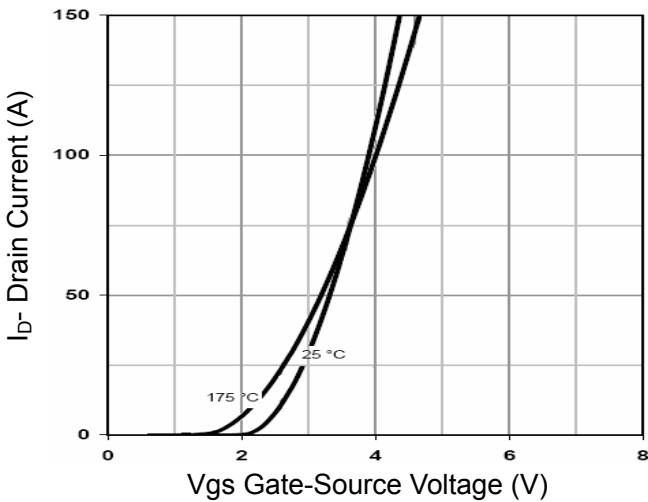


Figure 2 Transfer Characteristics

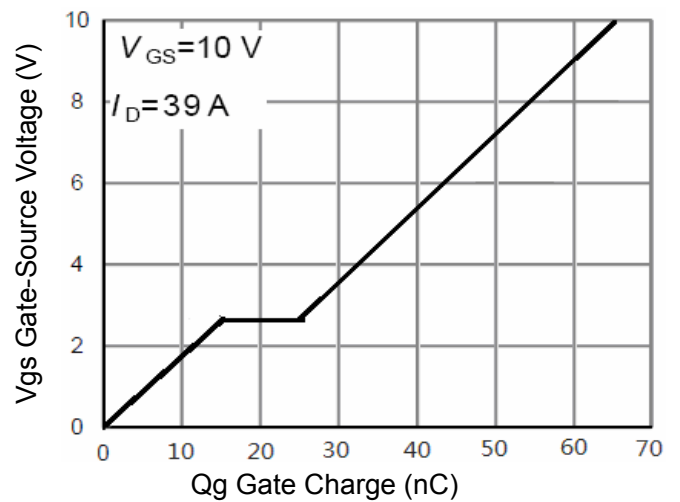


Figure 5 Gate Charge

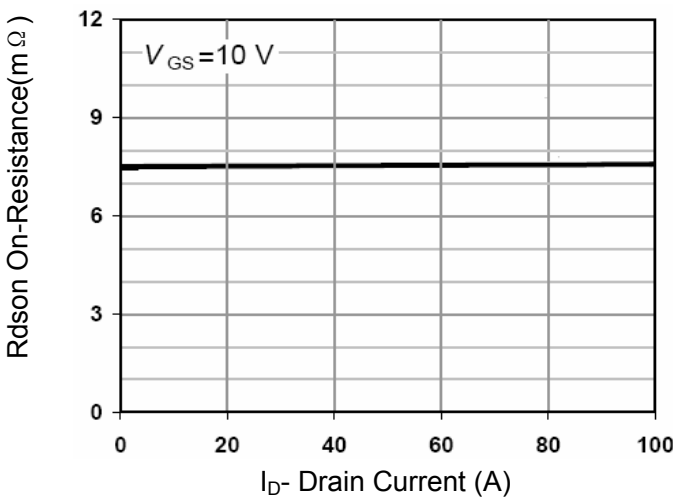


Figure 3  $R_{dson}$ - Drain Current

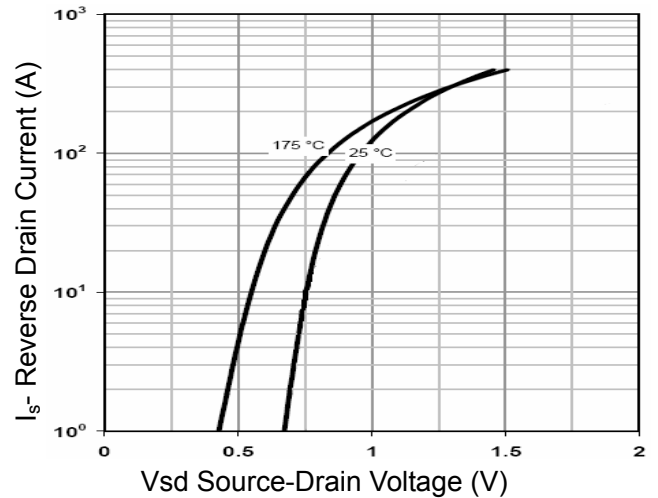


Figure 6 Source- Drain Diode Forward

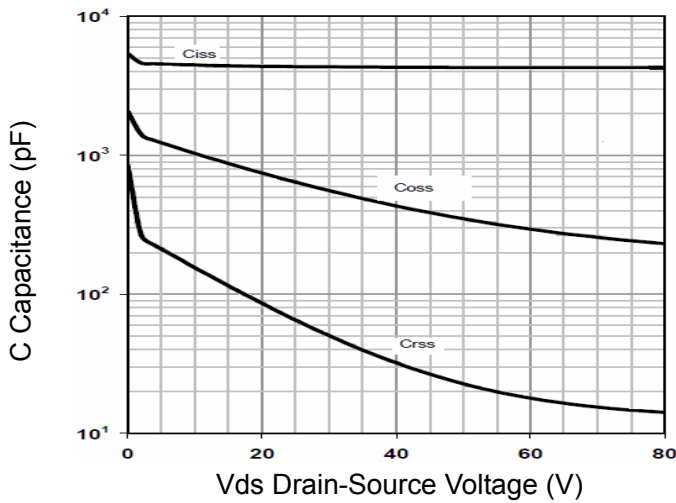


Figure 7 Capacitance vs Vds

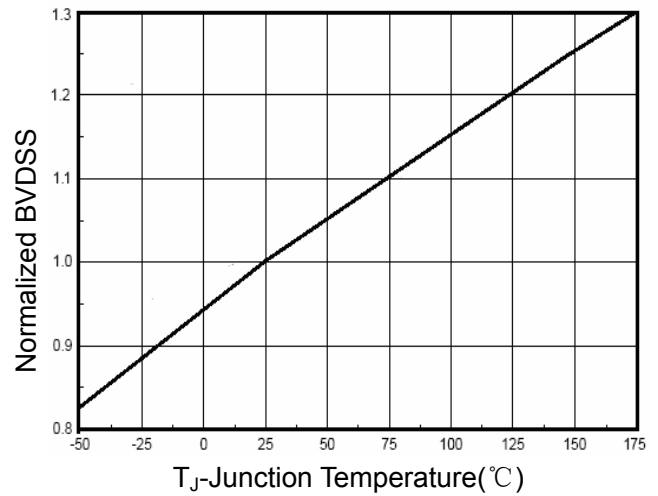


Figure 9 BV<sub>DSS</sub> vs Junction Temperature

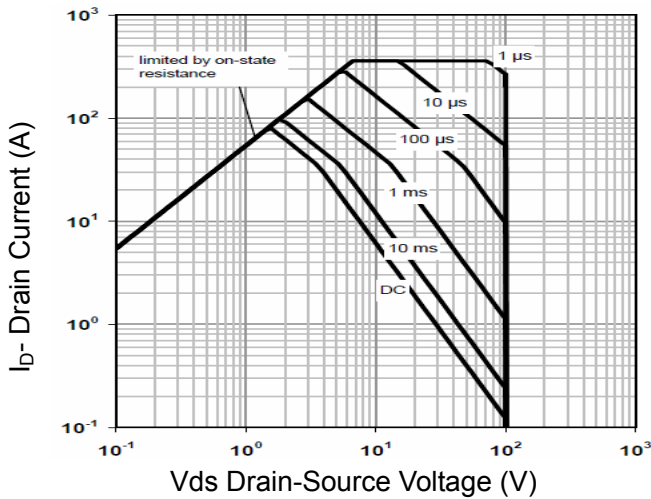


Figure 8 Safe Operation Area

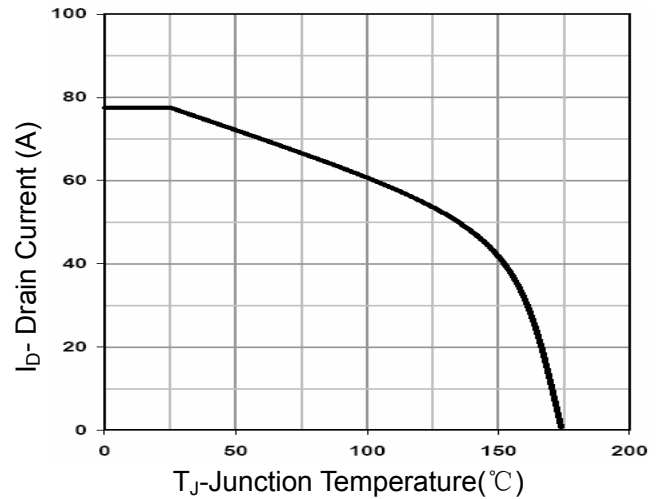


Figure 10 Current De-rating

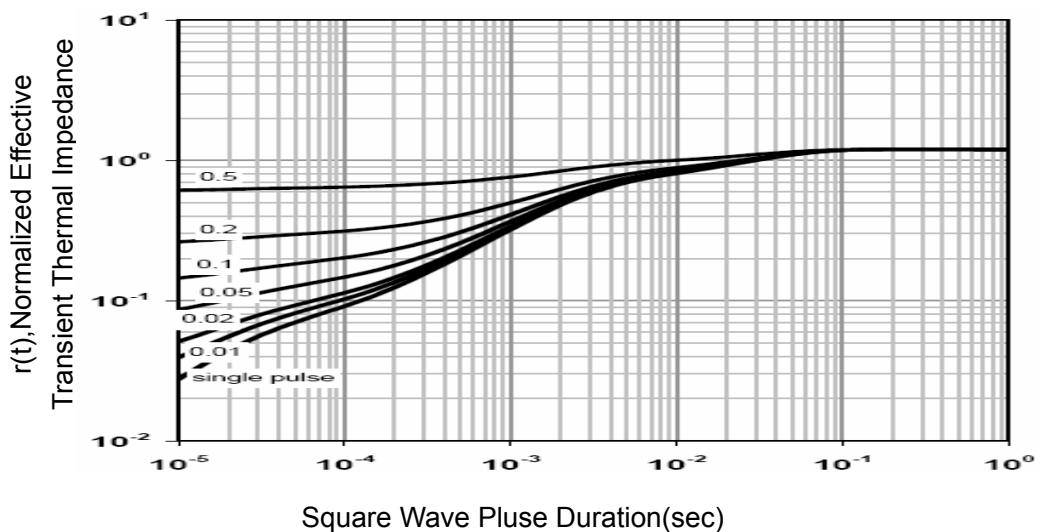


Figure 11 Normalized Maximum Transient Thermal Impedance

**TO-252 Package Information**


| Symbol | Dimensions In Millimeters |        | Dimensions In Inches |       |
|--------|---------------------------|--------|----------------------|-------|
|        | Min.                      | Max.   | Min.                 | Max.  |
| A      | 2.200                     | 2.400  | 0.087                | 0.094 |
| A1     | 0.000                     | 0.127  | 0.000                | 0.005 |
| b      | 0.660                     | 0.860  | 0.026                | 0.034 |
| c      | 0.460                     | 0.580  | 0.018                | 0.023 |
| D      | 6.500                     | 6.700  | 0.256                | 0.264 |
| D1     | 5.100                     | 5.460  | 0.201                | 0.215 |
| D2     | 4.83 TYP.                 |        | 0.190 TYP.           |       |
| E      | 6.000                     | 6.200  | 0.236                | 0.244 |
| e      | 2.186                     | 2.386  | 0.086                | 0.094 |
| L      | 9.800                     | 10.400 | 0.386                | 0.409 |
| L1     | 2.900 TYP.                |        | 0.114 TYP.           |       |
| L2     | 1.400                     | 1.700  | 0.055                | 0.067 |
| L3     | 1.600 TYP.                |        | 0.063 TYP.           |       |
| L4     | 0.600                     | 1.000  | 0.024                | 0.039 |
| Φ      | 1.100                     | 1.300  | 0.043                | 0.051 |
| θ      | 0°                        | 8°     | 0°                   | 8°    |
| h      | 0.000                     | 0.300  | 0.000                | 0.012 |
| V      | 5.350 TYP.                |        | 0.211 TYP.           |       |

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